Supporting information for the paper:

Effect of Carbon-skeleton Isomerism on Dielectric Property and

Proton Conduction of Organic Cocrystal Compounds Assembled

from 1,2,4,5-Benzenetetracarboxylic Acid and Piperazine Derivatives

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Powder X-ray Diffraction Patterns after Proton-conducting Measurements

D-H···A	d(D-H)	d(H…A)	d(D…A)	∠(DHA)		
OCC 1						
O(2)-H(2)-O(6a)	0.85	1.80	2.6368(15)	167		
O(4)-H(4A)····O(3b)	0.85	2.58	3.3660(17)	154		
O(7) - H(7) - O(3c)	0.85	1.78	2.6279(15)	172		
O(7)-H(7)···O(4c)	0.85	2.63	3.1517(15)	121		
O(1W)-H(1WA)-O(5)	0.903(17)	2.19(2)	3.014(2)	151		
$N(12)-H(2A)\cdots O(1Wd)$	0.89	1.89	2.778(13)	172		
N(12)-H(2B)····O(8e)	0.89	1.96	2.754(13)	148		
$N(14)-H(14C)\cdotsO(1Wc)$	0.97	2.29	3.064(4)	136		
N(14)-H(14D)····O(8f)	0.97	2.09	2.753(5)	124		
OCC 2						
O(1W)-H(1WD)O(14a)	0.85	2.49	3.0618(18)	126		
N(1)-H(1A)····O(11)	0.90	1.86	2.616(2)	141		
N(1)-H(1B)O(1W)	0.90	1.90	2.790(2)	172		
O(1)-H(1C)O(5a)	0.85	2.27	2.5834(17)	102		
O(1W)-H(1WC)-O(1b)	0.85	2.56	3.1865(17)	131		
O(1W)-H(1WC)-O(6a)	0.85	2.33	2.9118(18)	126		
N(2)-H(2A)-O(8a)	0.89	2.01	2.738(2)	138		
O(3)-H(3A)····O(7b)	0.85	2.55	3.2469(18)	140		
$O(7)-H(7A)\cdots O(4c)$	0.85	1.81	2.6145(19)	158		
O(12)-H(12C)···O(15b)	0.85	1.92	2.5268(19)	127		
O(13)-H(13A)····O(10d)	0.85	1.94	2.7239(18)	153		
O(16) - H(16A) - O(12c)	0.85	2.46	3.1702(19)	142		

Table S1. Hydrogen-bonding geometry parameters (Å, °) for OCC 1 and OCC 2

Symmetry codes : a)+x,+y,1+z; b)1-x, -y, -z; c) -1+x,1+y,+z; d)1-x,1-y, -1-z; e) -x, 2-y, -z; f) +x,+y,-1+z for OCC 1; a) -1+x, y, z; b) x,-1+y, z; c) x, 1+y, z; d)1+x, y, zfor OCC 2.



Fig. S1 A 2D supramolecular network with (4, 4) topology in OCC 1.



Fig. S2 The π - π stacking interactions of benzene rings in two adjacent layers in OCC 1.



Fig. S3 The cavity with dimensions of 5.497×8.062 Å² in OCC 1.



Fig. S4 A 2D supramolecular network with (4, 4) topology in OCC 2.



Fig. S5 The π - π stacking interactions of benzene rings in two adjacent layers in OCC 2.



Fig. S6 The cavity with dimensions of 5.486×8.040 Å² in OCC 2.



Fig. S7 IR absorption spectra of H_4 betc, Hopip and OCC 1 in the solid state at room temperature.



Fig. S8 IR absorption spectra of H_4 betc, Mepip and OCC 2 in the solid state at room temperature.



Fig. S9 The PXRD patterns for OCC 1 of a simulation based on single-crystal analysis and as-synthesized bulk crystals.



Fig. S10 The PXRD patterns for OCC 2 of a simulation based on single-crystal analysis and as-synthesized bulk crystals.



Fig. S11 Thermogravimetric curve for OCC 1.



Fig. S12 Thermogravimetric curve for OCC 2.



Fig. S13 The dielectric constant (ϵ') for OCC 1 measured as a function of temperature at various frequencies in the heating process.



Fig. S14 The dielectric constant (ϵ') for OCC 2 measured as a function of temperature at various frequencies in the heating process.



Fig. S15 The dielectric constant (ϵ') for OCC 1 measured as a function of temperature at various frequencies in the cooling process.



Fig. S16 The dielectric constant (ϵ') for OCC 2 measured as a function of temperature at various frequencies in the cooling process.



Fig. S17 The dielectric loss (tan δ) for OCC 1 measured as a function of temperature at various frequencies in the heating process.



Fig. S18 The dielectric loss (tan δ) for OCC 2 measured as a function of temperature at various frequencies in the heating process.



Fig. S19 The dielectric loss (tan δ) for OCC 1 measured as a function of temperature at various frequencies in the cooling process.



Fig. S20 The dielectric loss (tan δ) for OCC 2 measured as a function of temperature at various frequencies in the cooling process.



Fig. S21 The dielectric loss (tan δ) for OCC 1 measured as a function of frequency at various temperatures in the heating process.



Fig. S22 The dielectric loss (tan δ) for OCC 2 measured as a function of frequency at various temperatures in the heating process.









(c)

(d)





(f)

Fig. S23 Plots of the state of OCC 1 at (a) 36 °C(309 K), (b) 92 °C(365 K), (c) 100 °C (373 K), (d) 150 °C(423 K), (e) 180 °C(453 K), (f) 197 °C(470 K) in the process of melting point measurement.





(b)







(d)



(e)



Fig. S24 Plots of the state of OCC **2** at (a) 36 °C(309 K), (b) 111 °C(384 K), (c) 122 °C (395 K), (d) 150 °C(423 K), (e) 180 °C(453 K), (f) 197 °C(470 K) in the process of melting point measurement.



Fig. S25 The PXRD patterns for OCC 1 of samples after the dielectric measurement, as-synthesized and simulated from single-crystal.



Fig. S26 The PXRD patterns for OCC 2 of samples after the dielectric measurement, as-synthesized and simulated from single-crystal.

Raman frequency (cm ⁻¹)	Suggested assignment			
	OCC 1			
676(m)	$\gamma(-NH^{2+})^a$			
741(m), 773(m),782 (vw)	$\gamma(-NH^{2+})^{b}$			
800(m), 808(s)	$v_{asym}(O-HO)$			
1163(m)	β (C–H)			
1259(m), 1390(s)	$v_{asym}(-COO^{-})$			
1567(w), 1608(s), 1565(w)	$v_{sym}(-COO^{-})$			
1703(w)	$v(C=O) + \delta(OH)$			
OCC 2				
675(m)	$\gamma(-NH^{2+})^a$			
782(w), 792(w)	$\gamma(-NH^{2+})^{b}$			
800(m), 808(s)	$v_{asvm}(O-HO)$			
1167(s)	β(C-H)			
1261(vw), 1391(s)	$v_{asym}(-COO^{-})$			
1570(m), 1607(s)	$v_{\rm sym}(-COO^-)$			
1722(vw)	$v(C=O) + \delta(OH)$			

Table S2. Raman frequencies (cm⁻¹) of OCC 1 and OCC 2 and suggested assignment

^awagging mode; ^b twist mode; γ -deformation out of plane; ν_{asym} – asymmetric stretching; ν_{sym} - symmetric stretching; β –in-plane-bending; δ – deformation in plane; vw-very weak, w-weak, m-medium, s-strong.



Fig. S27 Temperature evolution of Raman bands of OCC 1 in the region of 600-1800 cm⁻¹.



Fig. S28 Temperature evolution of Raman bands of OCC 2 in the region of 600-1800 cm⁻¹.



Fig. S29 Nyquist plots of OCC 1 at different temperatures and ~97% RH (relative humidity).



Fig. S30 Nyquist plots of OCC 2 at different temperatures and ~97% RH (relative humidity).



Fig. S31 Temperature dependence of the conductivity (σ) for OCC 1 at ~97% RH.



Fig. S32 Temperature dependence of the conductivity (σ) for OCC 2 at ~97% RH.



Fig. S33 Nyquist plots of OCC 1 at different RH (relative humidity) and 298 K.



Fig. S34 Nyquist plots of OCC 2 at different RH (relative humidity) and 298 K.



Fig. S35 Nyquist plot of OCC 1 at ambient conditions and at 299 K.



Fig. S36 Nyquist plot of OCC 2 at ambient conditions and at 299 K.



Fig. S37 The PXRD patterns for OCC 1 of samples after the impendence measurement, as-synthesized and simulated from single-crystal.



Fig. S38 The PXRD patterns for OCC 2 of samples after the impendence measurement, as-synthesized and simulated from single-crystal.